

A computational analysis of a $\text{ZrO}_2\text{--SiO}_2$ scale for a $\text{ZrB}_2\text{--ZrC--Zr}$ ultrahigh temperature ceramic composite system

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Abstract

The success of a ceramic composite for ultrahigh temperatures (i.e., >1873 K) in an oxidizing atmosphere resides in the protective characteristics of a scale to limit oxygen ingress or to control the oxygen reaction into the substrate. With temperature changes from room temperature to ultrahigh temperatures, the mechanics of the scale and its reactivity becomes critical for ceramic composites to operate under extreme environments. A study was pursued to design computationally a $\text{SiO}_2\text{--ZrO}_2$ scale for a $\text{ZrB}_2/\text{ZrC}/\text{Zr--Si}$ composite by using conventional finite element analysis, which was used as a baseline microstructure for the extended finite element method. The model of the Zr boride/carbide composite with a $\text{SiO}_2/\text{ZrO}_2/\text{ZrSi}_x$ scale simulates the development of local strain energetics under a thermal load from 300 to 1700 K. The computational analysis determined that the size of the SiO_2 and ZrSi_x precipitates does not appreciably influence the durability of the microstructure. A simulated annealing optimization algorithm was also developed for an extended finite element program (called XMicro) with the purpose of optimizing the auto re-meshing of XMicro and thus minimizing its combinatorial selection of a composite's reinforcement architecture. After correcting for the overlapping of ZrO_2 precipitates within a matrix, XMicro determined that 1.96 μm as the optimal spacing of precipitates within a cluster and 20 μm between clusters within a silica matrix of the scale interphase. The strategic experimentation determined that porosity developed during oxidation should be incorporated into the simulation of a ceramic composite. To probe into the efficacy of the silica layer for the scale, oxidizing experiments were performed at 1973 K, as well as microstructural analysis of the scale interphase. The computational mechanics coupled with consideration of the thermodynamic stability of phases for the Zr--Si--O system to set the oxygen potentials between layers can design a scale interphase for an ultrahigh-temperature, ceramic composite system. The processing challenge would be to attain the optimal configuration of the microstructure, for example, silicide precipitates developed with the appropriate spacing along a scale/matrix interface or ZrO_2 clusters within a silicate phase.
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1. Introduction

In considering the computational modeling of the deformation of ultrahigh-temperature ceramic composites, the effects of crystal structure, elastic anisotropy, grain-boundary sliding and even slow crack growth on the strength of the composite are required. An understanding of the controlling mechanisms is critical especially when extrapolating from the available mechanical properties to predict the ultrahigh-temperature behavior, so a reasoning of the major parameters used are summarized here. The focus of the study was to model the mechanics

and thermodynamic stability of a $\text{ZrO}_2\text{--SiO}_2$ scale developed on a $\text{ZrB}_2\text{--ZrC--Zr}$ ceramic composite considering a thermal load from 300 to 1973 K with subsequent cooling. An assessment of the simulations becomes problematic because of limited strain and stress data, so the emphasis was to optimize the scale microstructure confirmed with a few experiments. Though the computational modeling evaluates the durability of the oxide scale from room temperature, the paper will direct its analysis of the oxide scale at temperatures greater than 1000 °C for which less data are available. For the deformation of ceramics at temperatures less than 1000 °C, the reader is referred to the critical reviews of Rice¹ on oxides, and the monograph by Wachtman² on ceramics.

1.1. Mechanics of the scale

The strength of ZrB_2 approximates 1.5 times better than ZrC at 1800 K, as determined by researchers^{3–8} and comparatively

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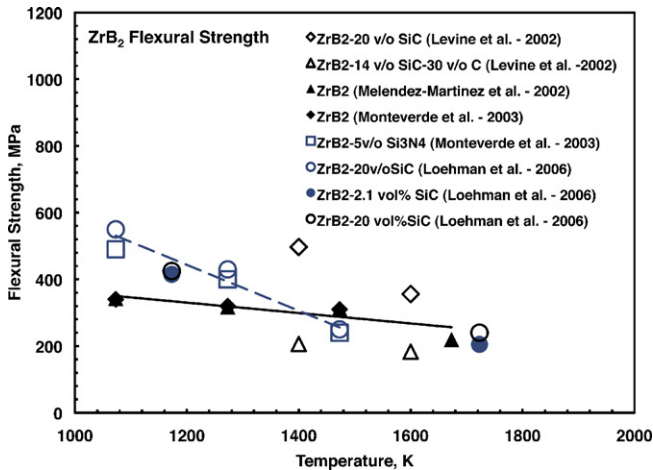


Fig. 1. The flexural strength of ZrB₂ used for the simulations of the ZrB₂/ZrC/Zr composite.

shown in Figs. 1 and 2. The flexural strength of ZrB₂ slightly decreases from 351 to 342 MPa at 298 to 1073 K, respectively, with more dramatic lowering of its strength to 219 MPa at 1673 K. The Si₃N₄ and SiC additions seem to increase the flexural strength at temperatures less than 1300 °C, though the strength of the ZrB₂ appear to extrapolate toward higher values than those attained by ZrB₂ with either Si₃N₄ or SiC beyond 1500 K. For ZrC, Gridneva et al.⁷ determined the flexural strength, but it is significantly less than the compressive yield stress as reported by Darolia and Archbold.⁸

The mechanics of a ZrO₂–SiO₂ scale was considered for simulation, because of its successful protective characteristics on a ZrB₂–SiC composite, as reported by Levine et al.,³ Hinze et al.,⁹ Opeka et al.,¹⁰ and Rezaie et al.¹¹ The scale consists of a dual layer interphase with an outer SiO₂ amorphous layer covering primarily a ZrO₂ layer with SiO₂ located within the grain boundaries at temperatures greater than 1773 K. Although a B₂O₃–SiO₂ liquid forms because of the eutectic temperature of 372 °C at 67 mol% B₂O₃,¹² boria vaporizes as the composite temperature rises to 1973 K. For example, a ZrB₂–30 vol% SiC mixture as investigated by Rezaie et al. becomes a 61 B₂O₃–39 SiO₂ (in mol%) composition assuming the ZrB₂–SiC reacts sto-

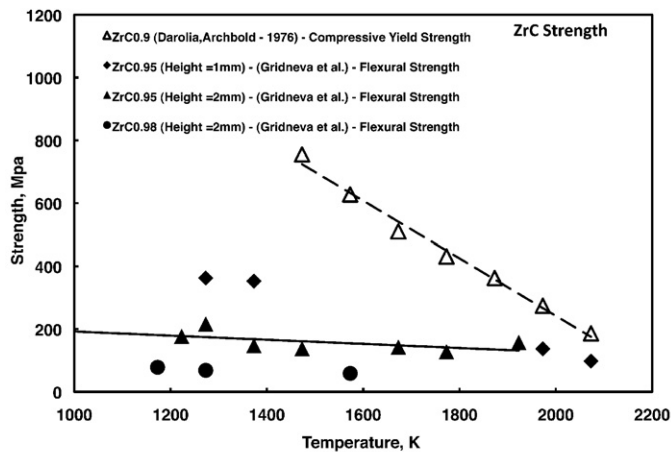


Fig. 2. The flexural strength of ZrC used for the simulations of the ZrB₂/ZrC/Zr composite.

ichiometrically upon oxidation. As the silicate liquid covers the surface and seals pores or grain boundaries, the silicate serves as an effective diffusion barrier to oxygen diffusion. Karlsdotir and Halloran¹³ more recently have reported the outer layer as a B₂O₃–SiO₂–ZrO₂ liquid with ZrO₂ precipitates. A key success to the protective borate–silicate scale from room temperature to 1973 K would be the molten phase covering a reactive boride–carbide substrate.

For the simulation of the ZrO₂ and SiO₂ within the scale, the mechanical properties for each phase were used, though its mechanics would depend on essentially three regions when considering the phase equilibria of the ZrO₂–SiO₂ system according to Muan.¹⁴ From room temperature to 1950 K, the zircon phase (ZrO₂·SiO₂) is stable until it incongruently transforms to ZrO₂ and SiO₂ phases, but the two-phase field only exists until 1960 K (1687 °C) where eutectic melting occurs at 5 wt% SiO₂. At temperatures greater than 1687 °C, liquid silica would equilibrate with the ZrO₂ phase as expected from the phase diagram. In addition, with impurities collecting in the grain boundaries, the SiO₂ phase would probably melt below its melting point of 1723 °C, which is usually reported for phase diagrams containing silica,¹⁴ or the recent calculated melting temperature of 1725 °C according to Schnurre et al.¹⁵ The flexural strength of SiO₂ steadily increases from 70 MPa at 300 K to 95 MPa at 2000 K according to Borodai.¹⁶

The flexural strength and elastic modulus of ZrO₂–6.5 mol% Y₂O₃, as reported by Adams et al.¹⁷ was reviewed to determine the possible deformation mechanisms of a ZrO₂ layer of the scale. Rice noted the similar behavior of ZrO₂–MgO and ZrO₂–Y₂O₃ in that the fracture modes are primarily transgranular at 300 K and intergranular at temperatures beyond 1773 K with mixed transgranular and intergranular at 1273 K. Although the flexural strength for sintered ZrO₂–Y₂O₃ of Rice et al.¹ plateaus from 1000 to 1500 °C, the intergranular fracture mode agrees that grain-boundary sliding controls creep of ZrO₂–Y₂O₃, even achieving superplasticity, at temperatures beyond 1273 K as reported by Rice,¹ Jiménez-Melendo et al.¹⁸ Jiménez-Melendo and Domínguez-Rodríguez¹⁹ (hereafter JM–DR)]. A debate ensues on whether an interface-reaction process develops as proposed by Owen and Chokshi,²⁰ a modified Coble mechanism as suggested by Berbon and Langdon²¹ or grain-boundary sliding controls superplasticity for ZrO₂–Y₂O₃ according to JM–DR. An extensive analysis by JM–DR provides a compelling explanation for the segregation of yttrium at the grain boundary affecting deformation, even with impurity or minor addition levels of SiO₂. For a tetragonal ZrO₂–Y₂O₃–5 wt%SiO₂, Kajihara et al.²² reported that deformation at 1500 °C occurs via a grain-boundary sliding with the silicate phase accommodating the stresses. Hence, the data needed for 1700 °C was extrapolated from ZrO₂–Y₂O₃ considering that grain-boundary sliding would control the deformation, as suggested by JM–DR. As a further consequence, the computational model would consist of a ZrO₂ layer with the SiO₂ phase located primarily within the grain boundaries with minimal reaction between phases.

A comparison of the hot-pressed and sintered zirconia as reported by Adams et al. are shown in Fig. 3. The properties

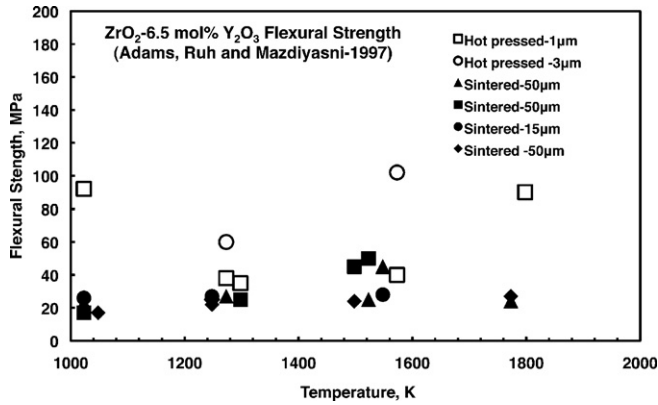


Fig. 3. The flexural strength of ZrO_2 used for the simulations of the $ZrB_2/ZrC/Zr$ composite.

for a sintered rather than a hot-pressed structure were selected for modeling, because the growth of the ZrO_2 layer on a scale would develop without any external stresses.

In the computational approach we are looking at the local strain energy as the quantity we wish to minimize. This is normalized in the phases by the flexural strength strain energy (flexural stress times the strain) of the phase to give a method of comparison between the phases. We do not explicitly consider fracture since we are looking for microstructures that minimize the damage energetics. The foregoing synopsis provides only part of the material properties (including the elastic moduli, coefficients of thermal expansion, and Poisson's ratio) used in the modeling of the scale mechanics with the thermal properties (e.g., thermal conductivity, specific heat capacity), as well as density, for the components of the composites. The experimental data are considerable and the reader is referred to Petla²³ for further study of the data.

1.2. Reactivity of the scale

The growth of the scale would be controlled primarily by the diffusion of the oxygen limited by the boundary conditions of the gas phase and the scale/matrix interface as similarly observed for scales on metals, according to the parabolic rate law. The established scale development has been classically explained by Wagnerian oxidizing behavior²⁴ by the following equation

$$\frac{1}{A} \frac{d\tilde{n}}{dt} = \frac{1}{\xi} \left[\frac{\tilde{c}}{2} \int_{p_{O_2}^{(i)}}^{p_{O_2}^{(o)}} \left(\left(\frac{Z_M}{Z_O} \right) D_M + D_O \right) d \ln p_{O_2} \right] = \frac{\tilde{k}}{\xi} \quad (1)$$

The foregoing equation considers the rate of equivalents (\tilde{n}) migrating per area (A) across an oxide thickness (ξ) with the self-diffusion coefficient of oxygen (D_O) and cations (D_M) integrated over the oxygen potential (i.e., $d \ln p_{O_2}$). Wagner's rational rate constant (\tilde{k}) with the units of equivalents/(cm s) is usually converted to the parabolic rate constant (k_p , cm^2/s). For further explanation of Wagner's parabolic rate law, the reader can refer to Wagner,²⁴ Yurek²⁵ and Kofstad.²⁶ The former rate constant with the concentration of equivalents (\tilde{c} , equivalents/ cm^3) can

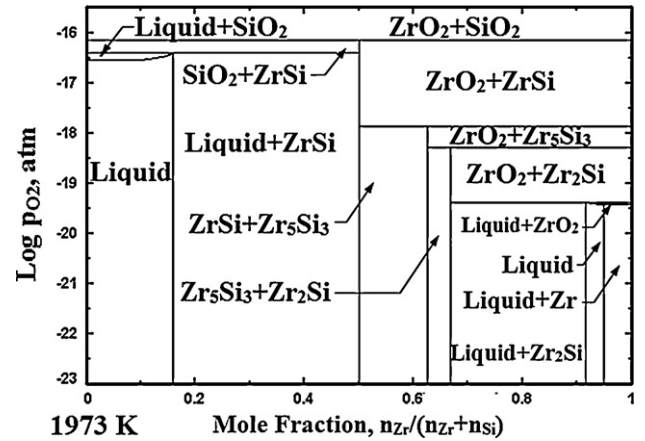


Fig. 4. The Zr–Si–O phase diagram considering the oxygen potential of the coexistence of phases at 1973 K.

be easily converted to k_p (i.e., $\tilde{k}/\tilde{c} = k_p$). The limiting criteria for the integral represents the thermodynamic activities, in this case the oxygen potential at the gas/scale interface ($p_{O_2}^{(o)}$) and the scale/layer interface ($p_{O_2}^{(i)}$). Hence, scale growth of a ceramic composite would depend on the diffusivity of the ionic defects in the zirconia phase (or O_2 within liquid silica) and the oxygen differential (i.e., $d \ln p_{O_2}$) with its boundary conditions established by the oxygen potential (i.e., $p_{O_2}^{(o)}$ and $p_{O_2}^{(i)}$) determined usually by the phase equilibria.

Silicide precipitates were also considered as part of the scale interphase on the premise that a three-phase field would establish the oxygen potential and thus control oxygen ingress through the scale. At 1700 °C, the oxygen flux will be controlled by two oxygen potentials – one determined by the gas phase and one fixed by a three-phase field consisting ZrO_2 – $ZrSi(s)$ – $SiO_2(l)$. In terms of the Gibbs phase rule for the Zr–Si–O system, the phase assemblage creates a bivariant situation ($F = C - P + 2 = 3 - 3 + 2 = 2$), but with the temperature defined and at atmospheric pressure, the assemblage becomes invariant. A similar fixation of the oxygen potential occurred at 2000 °C for a ZrO_2 phase coexisting with silicide and silicate liquids as reported by Peña et al.²⁷ In addition to slowing the oxygen transport through silica, Peña et al. reported that the silicide coating survived for more than 49 h, because of the fixation of the oxygen potential.

The effect of the three-phase equilibrium is more easily apparent with a calculated phase diagram depicted according to the Zr mole fraction and the partial pressure of oxygen at 1973 K, as shown in Fig. 4. The horizontal lines actually show constant oxygen potentials such as the ZrO_2 – SiO_2 – $ZrSi$ equilibrium occurring at the highest oxygen partial pressure ($\log p_{O_2} = -16.2$). The next lower oxygen potential with three-phase equilibrium for solid phases corresponds to the $ZrSi$ – Zr_5Si_3 – ZrO_2 coexistence at $\log p_{O_2} = -17.9$.

The Zr–Si–O phase diagram was calculated via the FactSage database and software (version 6.1),²⁸ which also incorporated the Scientific Group Thermodata Europe (SGTE) database. However, the Okamoto phase diagram²⁹ shows the eutectoid temperature for Zr_5Si_3 at 1745 °C (2018 K); the SGTE database gives it at 1433 °C (1806 K). In addition, the Okamoto phase

diagram does not show the $Zr_5Si_3 + ZrSi$ phase-field bounded by the following SGTE eutectic reaction at 2407 °C (2680 K) and the peritectoid reaction at 1660 °C (1933 K), respectively:



Further analysis of the differences in phase equilibria is needed for temperatures greater than 1973 K, especially 2680 K, but these temperatures are not the focus of the present evaluation.

Although three-phase equilibrium within the scale interphase would decrease oxygen ingress as established by the Wagnerian rate law (Eq. (1)), the effect of silicide-precipitate size on the strain energetics within the scale interphase should also be considered. The scale must also withstand subsequent temperature cycling causing dramatic changes in the strain distribution along the interphase. In the present study, the local strain energetics was used to infer an optimal scale configuration knowing that it is an initial step in understanding oxidation at extreme temperatures by coupling scale mechanics and reactivity.

A computational approach then validated with strategic experimentation is not new and has recently been applied in designing alumina–carbaceous (A–C) and mullite–carbaceous (M–C) refractories³⁰ and ZrB_2 and ZrB_2 –30%SiC composites³¹ for thermal shock resistance. Finite element models were used to simulate the effect of temperature gradients on the stresses of the composite during a temperature change. For example, the thermal expansion coefficient was higher for an A–C refractory than for a M–C refractory and caused by higher stresses for the former. However, the stresses were offset by a lower temperature gradient for A–C than for M–C because the thermal conductivity was higher for the A–C refractory. For ZrB_2 and ZrB_2 –SiC, the thermal shock resistance was determined experimentally as similar. In the finite element analysis of ZrB_2 –SiC, Zimmermann et al.³¹ reported that the low heat transfer between the SiC particles and the surrounding ZrB_2 matrix caused residual stresses to develop. In both studies, the finite element analyses revealed specific attributes of the interaction between temperature gradients and stresses sometimes not discerned in an experimental study. However, studies coupling the computational mechanics with the computational thermodynamics have been limited, especially at ultrahigh temperatures.

2. Computational approach

2.1. Damage modeling of scale interphase with non-linear finite element analysis

The durability of the ZrO_2 – SiO_2 scale on a ZrB_2 – ZrC – Zr composite at ultrahigh temperatures was simulated with a mesh generated by Altair HyperMesh for the conventional finite element software of the LS-DYNA code developed by Livermore Software Technology Corporation (LSTC). The mesh was drawn manually with an element size approximating 2 μm with a configuration shown in Fig. 5. The mesh consisted of dual layers of SiO_2 and ZrO_2 as the scale interphase with a thickness of 50 and 80 μm , respectively, for a ZrB_2 – ZrC – Zr substrate, as

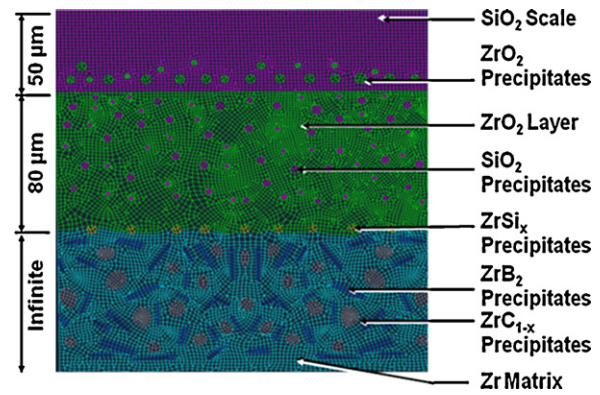


Fig. 5. The baseline mesh used for conventional finite element analysis considering a dual layer of SiO_2 and ZrO_2 layer protecting an underlying $ZrB_2/ZrC/Zr$ composite.

shown in Fig. 5. Silicide precipitates were embedded within the zirconia layer near the ZrO_2 /matrix interface to complete the baseline mesh of the ZrO_2 – SiO_2 scale on a ZrB_2 – ZrC – Zr matrix or substrate.

The thermal load onto the scale/substrate was applied with a temperature rise from 300 to 1973 K within a hour, an isothermal hold for 6 h at 1973 K followed by an expected convective cooling of a solid, as shown in Fig. 6. The temperature cycle was selected according to the usual oxidizing studies. An adiabatic process was assumed after simulating two scenarios—one with temperature defined at the surface with heat conduction developing inwardly to the substrate and another case in which the temperature was defined for all the nodes. The strain and stress had no significant difference for both cases with a scale thickness totaling 130 μm .

Physical, mechanical and thermal properties of each of the phases depicted in the baseline mesh required for the code were: density, Young's modulus, Poisson's ratio, yield stress, coefficient of thermal expansion, thermal conductivity and specific heat capacity, as available by Petla.²³ The mechanical properties at ultrahigh temperatures are sparse so assumptions were made in most cases by extrapolating properties at the available temperatures or substituting for related parameters (e.g., flexural strength for yield stress). One must be aware sometimes of the complicated relationship between flexural and tensile stress, as Marshall and Evans³² have reported. As an example of a parameter assumption, the elastic modulus for ZrB_2 was con-

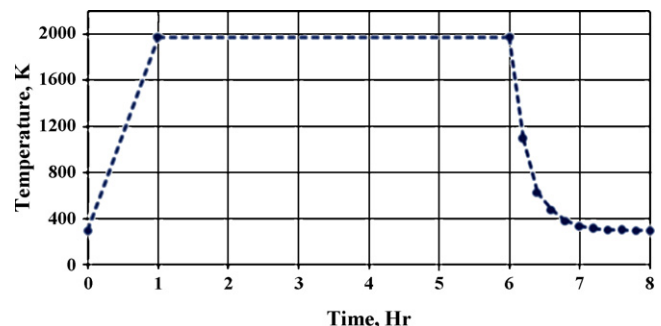


Fig. 6. The thermal cycle used to load the composite for the simulations.

Table 1
Elastic moduli of components used for modeling.

Material	Density (g/cm ³)	Elastic modulus (GPa)						
		Temperature (°C)						
		20	200	500	800	1100	1400	1700
ZrO ₂	5.62	222	213	178.5	179	178	169	160.5
ZrB ₂	5.28	346	346	346	346	346	346	346
ZrC	6.605	390.3	387.4	379.5	368.7	358.9	344.2	326.6
SiO ₂	2.21	72.4	73.5	75.6	77.9	79.4	80.4	81.6
Zr	6.49	106	94	74	54	24.42	24.42	24.42
Ti ₅ Si ₃	4.32	156	155	153	145	142.2	137.7	133.2
ZrB ₂ /ZrC/Zr	6.2	286	253	199	145	64	64	64

sidered unchanged because of its crystal structure and strength behavior with increasing temperature (Fig. 1). In addition, the elastic modulus of ZrB₂ is reasonable when the elastic moduli of the components do not vary significantly, especially ZrC, as shown in Table 1. For the coefficient of thermal expansion, the individual components of the components were used as shown in Table 2. For more information, the reader is referred to Petla who has summarized the parameters for the mechanical and thermal properties of the components.

The yield stress of zirconium disilicide is available but with a melting point of 1620 °C (or 1893 K), its usage requires a small extrapolation to 1973 K. The four silicides (e.g., ZrSi, Zr₅Si₄, Zr₃Si₂, Zr₅Si₃ and Zr₂Si) located in the middle of the Zr–Si phase diagram are stable at 1973 K, though their yield stress or flexural strengths were not found after an extensive search in the literature. Umakoshi et al.³³ have determined the yield stress for a Ti₅Si₃ single crystal, which was considered a valid substituting constituent for the Zr silicide because of titanium's proximity to Zr on the periodic table. Although the multivalency of Ti differs from Zr, the Zr₅Si₃ phase with the same hexagonal structure of Ti₅Si₃ has a similar fracture toughness determined through microindentation as Ti₅Si₃ according to Ikarashi et al.³⁴. Hence, the data for the yield strength of Ti₅Si₃ acquired by Frommeyer and Rosenkranz³⁵ were used for the simulations after comparing results from researchers^{33–37} because of the wider temperature range, as shown in Fig. 7.

Table 2
Coefficients of thermal expansion of components used for modeling.

Material	Coefficient of thermal expansion, 10 ⁶ /(K)						
	Temperature (°C)						
	20	200	500	800	1100	1400	1700
ZrO ₂	8.8	9.8	10.6	11.21	12.1	13.01	13.91
ZrB ₂	6.7	6.7	6.89	7.11	7.34	7.56	7.79
ZrC	5.6	5.6	5.9	6.6	7	7.2	7.3
SiO ₂	0.51	0.57	0.58	0.52	0.51	0.51	0.51
Zr	5.74	5.98	6.47	7.1	6.3	7.57	8.86
Ti ₅ Si ₃	6.7	7.3	8.25	8.5	8.77	9.16	9.7
ZrB ₂ /ZrC/Zr	6.6	6.6	6.8	6.9	7.1	7.1	7.1

2.2. Strain modeling of SiO₂–ZrO₂ layer with extended finite element analysis

The extended finite element or enriched method predicts the strain and stress distribution along discontinuities such as inclusions or cracks without remeshing the microstructure as reported by Sukumar et al.³⁸ The enriched method consists of adding functions to the scalar variable $u(x)$ whereby only the elements near the discontinuities, such as ZrO₂ precipitates in a silica layer in the present study, are enriched. The additional function for interface discontinuities is the absolute value $f_a(X)$, which is the level set function or the signed distance from any point normal from the ZrO₂ precipitate and a_i is the unknown scalar variable of a node in the enrichment zone simulated as reported by Belytschko et al.³⁹

$$u(x) = \sum_1 N_i(x)(u_i + a_i |f_a(x)|) \quad (4)$$

whereas, the formula for a continuous surface is only

$$u(x) = \sum_1 N_i(x)(u_i) \quad (5)$$

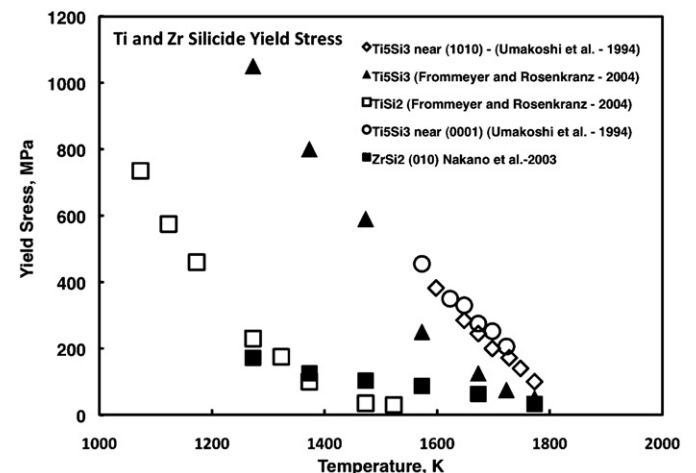


Fig. 7. The yield strength of silicides used for the simulations of the ZrB₂/ZrC/Zr composite.

Table 3
Properties of SiO₂ and ZrO₂ constituents.

Material	Young's modulus (GPa)	Poisson's ratio	Density (kg/m ³)	Coefficient of thermal expansion, 10 ⁶ /(K)
Silica	74.0	0.17	2200	0.6
Zirconia	186	0.33	6040	8.2

for which N_i represents the finite element method for regular shape functions.

An extended finite element code, named XMicro, was developed to compute the thermal stresses on standard elements by considering the initial strain resulting from a temperature rise. The linear elastic plane strain (ε) is:

$$\varepsilon = B^T d \quad (6)$$

where B is the nodal sub-matrix and d is the displacement matrix. The strain energy at each node is then calculated as an objective function,

$$U_t = \sigma_{11}\varepsilon_{11} + \sigma_{22}\varepsilon_{22} + 2 * \sigma_{12}\varepsilon_{12} \quad (7)$$

where σ is the stress of the element.

The simulations using XMicro consisted of ZrO₂ precipitates embedded in a silica matrix. Although the regular finite element analysis considered a thermal load of 300–1973 K, the extended finite element analysis considered a reference temperature of 573–1073 K with the mechanical and physical properties shown in Table 3. For optimization purposes, the range of the volume fraction was restricted to 10–50% of ZrO₂ with their number restricted to 16. The aspect ratio ranged from 0.1 to 10 with the former representing a horizontal ZrO₂ precipitate within a silica matrix and the latter is a vertical precipitate. The domain of the SiO₂ matrix was fixed at a 900 μm^2 grid meshed with 0.25 μm sized triangular elements.

3. Experimental approach

To validate the modeling, a composite of ZrB₂/ZrC/Zr–Si was formed by infiltrating molten Zr–Si (2.1 g) into a packed bed of B₄C particles (i.e., <10 μm diameter and 0.25 g) contained in a carbon crucible heated to approximately 2200 °C with an induction furnace shown in Fig. 8. The process extends essentially the technique developed by Johnson et al.⁴⁰ who originally reacted liquid Zr with B₄C particulates at 1900 °C to acquire a pore free composite of ZrB₂/ZrC/Zr. The liquid Zr reacts with the carbide according to the following exothermic reaction:



Although a stoichiometric reaction is shown, an excess amount of Zr can be used to serve as a matrix containing the boride and carbide. Johnson et al.⁴⁰ also infer that the temperature of the Zr/B₄C interface may reach 2300–2400 °C even though the furnace temperature was set at 1900 °C. In the present study, the molten Zr serves as the carrier for the Si with the expectation of developing a ZrO₂–SiO₂ scale on the composite.

Samples were oxidized in a MoSi₂ furnace at 1700 °C in air. The temperature of the samples was raised to 1700 °C in

4 h, maintained at 1700 °C for 44 or 48 h and decreased to room temperature in approximately 4 h. A ZrB₂/ZrC/Zr–Si composite was simply placed on a zirconia refractory pedestal then heated to temperature. A Pt/Pt–10 wt%Rh thermocouple placed adjacent to sample was used to check the furnace temperature, which was controlled with a Pt–20 wt%Rh/Pt–40 wt% Rh thermocouple. The measuring thermocouple was removed intermittently to minimize Pt or Rh vaporization after measuring temperatures at 1100–1600 °C at approximately 100° increments. To ensure the development of a SiO₂ layer, another composite sample (1.2 g) was also placed within a quartz tube (1 cm outside diameter, 8 mm inside diameter), evacuated and sealed with a hydrogen–oxygen torch. The encapsulated composite was then heated to 1700 °C and maintained for 48 h. At approximately 1650 °C, the quartz wall collapsed and surrounded the composite with a SiO₂ layer of 1 mm thickness. To determine the stability of the SiO₂ layer, Zr metal (0.2 g) and ZrSi₂ powder (0.3 g) were similarly encapsulated and annealed for 44 h at 1700 °C.

The quartz ampoules were placed on ZrO₂–8 wt% Y₂O₃ chips contained in an alumina crucible and then heated to 1700 °C. The quartz contacted the ZrO₂–Y₂O₃ surfaces to minimize the formation of a Al₂O₃–SiO₂ melt resulting from its eutectic (i.e., 1587 °C), but instead a ZrO₂–SiO₂ melt approximating 97 wt% SiO₂ would stabilize at 1700 °C.

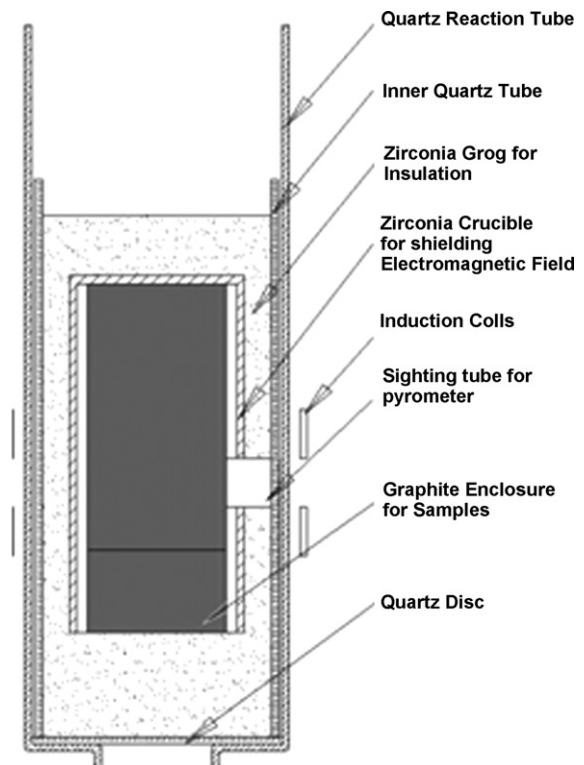


Fig. 8. Experimental setup within induction furnace.

For microstructural characterization, samples were prepared metallographically to a 1 μm diamond polish for examination in a field-emission, scanning electron microscope (Hitachi S-4800). In addition, an energy dispersive X-ray microanalysis (EDAX with Gensis software) provided qualitative elemental analysis, which was augmented with known phase diagrams (e.g., Peña et al.²⁷ for Zr–Si–O and Okamoto²⁹ for Zr–Si) to determine the phases within the microstructure.

4. Results

The simulation of the strain for the interphase (depicted in Fig. 5) was calculated via a design of experiments (DOE) factorial study. The number of simulations (*N*) considered one replica (*R*), two levels (*L* = 2) of importance of high and low extremes of the effect of parameters or factors (*k* = 3) consisting of ZrB₂ fibers, ZrC precipitates, ZrO₂ precipitates and ZrSi_x precipitates, as summarized in Eq. (9).

$$N - RL^k = 1(2)^3 = 8 \tag{9}$$

The eight simulations amounted to four low levels of the baseline mesh, and for the high level, the parameters were increased by 100%. The ZrB₂ fibers and ZrC precipitates amounted to 20% of the area considered as a low level within the ZrB₂–ZrC–Zr matrix and 30% as the high level. The area of the ZrSi_x precipitates amounted to 17 μm as the low level and 30 μm for a high level simulation.

The eight simulations indicated that the size of the ZrB₂ and ZrC phases contributed significantly to the maximum strain, as shown in Fig. 9. The four simulations with the smaller areas of the boride and carbide precipitates developed lower strains than the four simulations with meshes containing larger precipitates. The effect of the silicide precipitates on the interface strain was apparent in models 1 and 2 in which a larger ZrSi_x area increased the strain when the areas of the ZrB₂, ZrC and ZrO₂ constituents maintained at lower levels. However, the ZrO₂ area or layer did not dramatically influence the calculated strain when considering the eight simulations in either the low or high levels. In addition, the silicide precipitates along the scale/matrix inter-

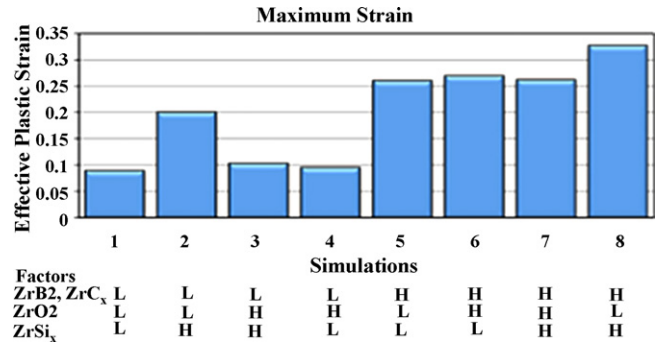


Fig. 9. The maximum strain acquired for high and low configurations of the ZrB₂, ZrC and Zr silicides.

face did not affect significantly the strain especially when the microstructural areas of the boride and carbide precipitates were at the higher levels. A comparison of the strain distributions for models 4 and 5 indicates that the ZrO₂ layer acquired less strain approximating 0.04 to 0.05 for the former than for the latter (approximating 0.13 to 0.2), as shown in Figs. 10 and 11.

For the enriched finite element method, a simulated annealing optimization algorithm was implemented to determine a preferred distribution of ZrO₂ precipitates within the silica layer. To confirm the accuracy of XMicro simulation, the calculated strains for one precipitate within SiO₂ were compared with a regular finite element method using a Hypermesh software, as shown in Fig. 12. The strains determined with XMicro for the *x*-, *y*- and *xy*-direction are within 10% of the strains calculated with Hypermesh indicating an accurate simulation of the enriched finite element method. Then, the strain energies for one and five precipitates randomly distributed were calculated with the minimal standard deviation for which typical results are shown in Fig. 13.

Next, XMicro was used to determine the optimal strain configuration of 16 ZrO₂ precipitates ranging from 10% to 50% within a SiO₂ matrix were successfully calculated with XMicro. The aspect ratio of the ZrO₂ precipitates ranged from 0.1 to 10 with their size varying from 1.8 to 90 μm within a SiO₂ domain of 900 μm. The minimum strain energies corre-

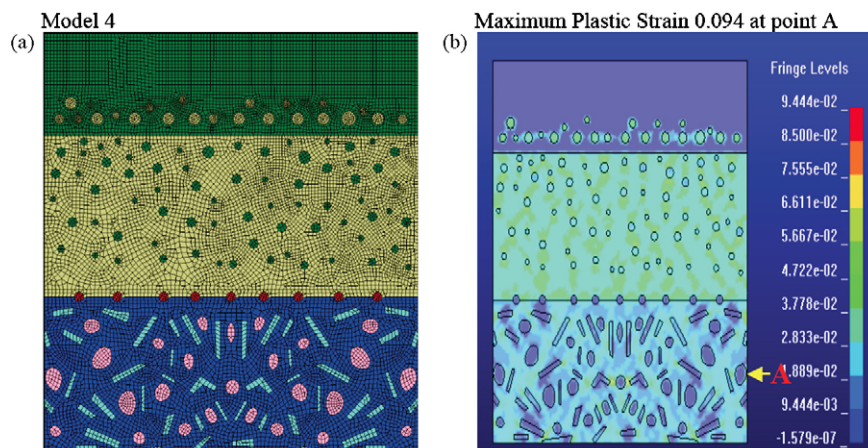


Fig. 10. Strain distribution of low configurations of a ZrB₂/ZrC/Zr composite with (a) showing the mesh and (b) the corresponding strain distribution.

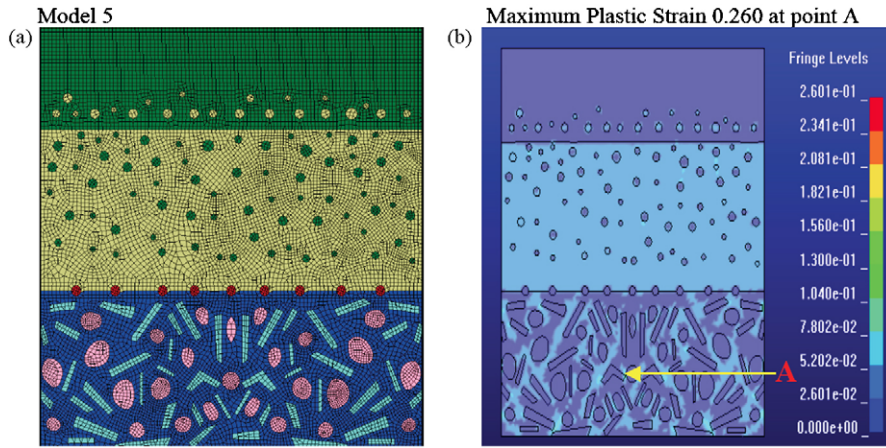


Fig. 11. Strain distribution of high configurations of a ZrB₂/ZrC/Zr composite with (a) showing the mesh and (b) the corresponding strain distribution.

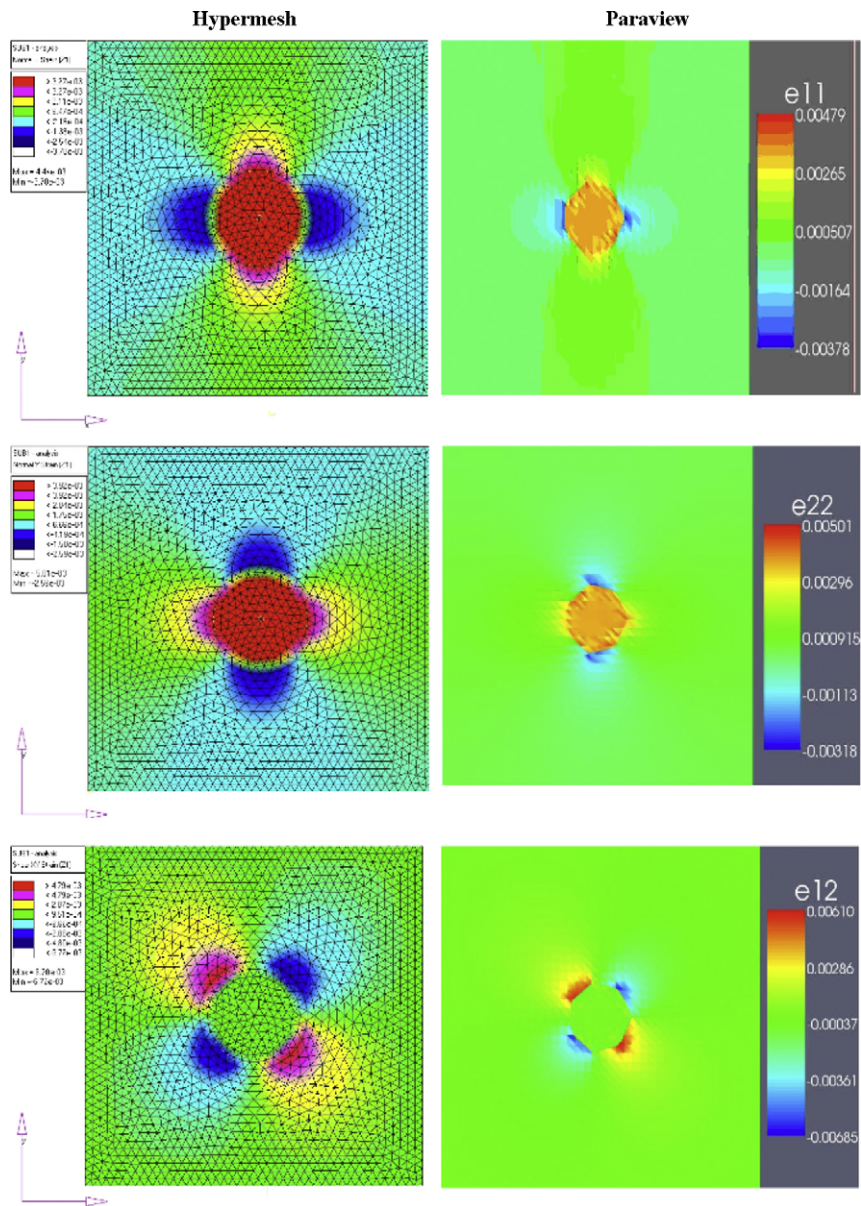


Fig. 12. Comparison of the Hypermesh finite element analysis with an extended finite element method with (a) e11, (b) e22 and (c) e12.

Table 4
Minimum strain energies of SiO₂ constituents within ZrO₂ layer.

Size of precipitates (μm)	Aspect ratio	Area of precipitates (μm)	Volume fraction	Strain energy (GPa/m ³)
1.69	8.56	6.2	0.11	0.0137
1.74	8.34	6.8	0.12	0.0142

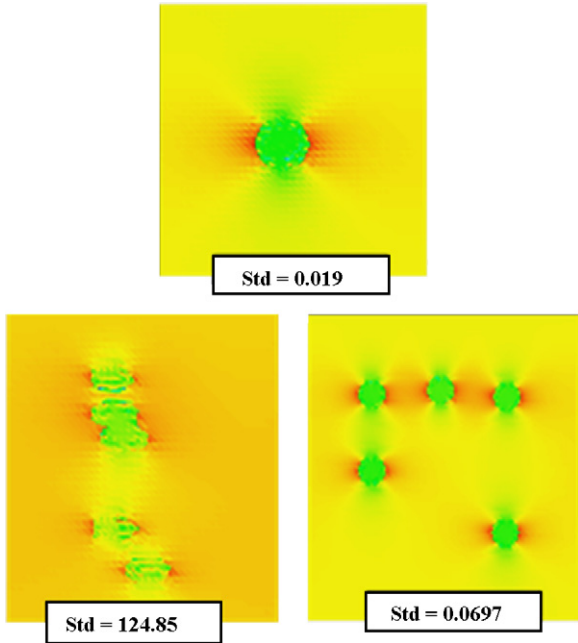


Fig. 13. Random particles distributed among a silica matrix for strain energies with standard deviations of (a) 0.019, (b) 124.85 and (c) 0.0697.

sponded to precipitate sizes of 1.69 and 1.74 μm, as shown in Table 4.

The optimal configuration of ZrO₂ precipitates distributed in clusters in a silica layer, as shown in Fig. 14. The spacing between clusters of ZrO₂ precipitates amounted to 20 μm with

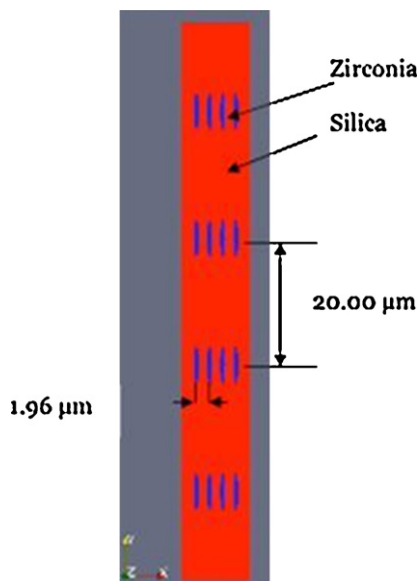


Fig. 14. SiO₂–ZrO₂ layer considering the optimal distribution of ZrO₂ clusters.

a 1.96 μm spacing between ZrO₂ precipitates for consideration of the mechanics of the scale. For the solid silicate phase containing ZrO₂ precipitates, their spacing of 20 μm is considerably less than that found experimentally for the silicate liquid layer of ZrB₂–SiC as reported by Karlsdottir and Halloran.¹³ The spacing of ZrO₂ nodules within the liquid boron–silicate melt ranged from 75 to 150 μm, but the spacing may result from Ostwald ripening facilitated by the liquid phase.

5. Discussion

The model of the Zr boride/carbide composite with a SiO₂/ZrO₂/ZrSi_x scale simulates the development of the local strain energetics under a thermal load from 300 to 1700 K. The size of the ZrB₂ and ZrC precipitates creates a maximum strain on the substrate as determined by conventional finite element analysis. The computational analysis using regular finite element analysis determined that the size of the SiO₂ and ZrSi_x precipitates does not appreciably influence the durability of the microstructure. The inconsequential effect of the ZrSi_x precipitates on the strain distribution may result from the metal fraction amounting from 70% to 80% within the composite containing Zr, ZrB₂ and ZrC.

To confirm the microstructural development of the scale on the substrate, a ZrB₂/ZrC/Zr–Si composite was created by reacting a Zr–Si melt with B₄C at approximately 2200 °C, as previously described. A typical acquired microstructure of the matrix consisting of ZrB₂ and ZrC precipitates dispersed in a Zr–Si metal matrix is shown in Fig. 15. The ZrC/ZrB₂/Zr–Si

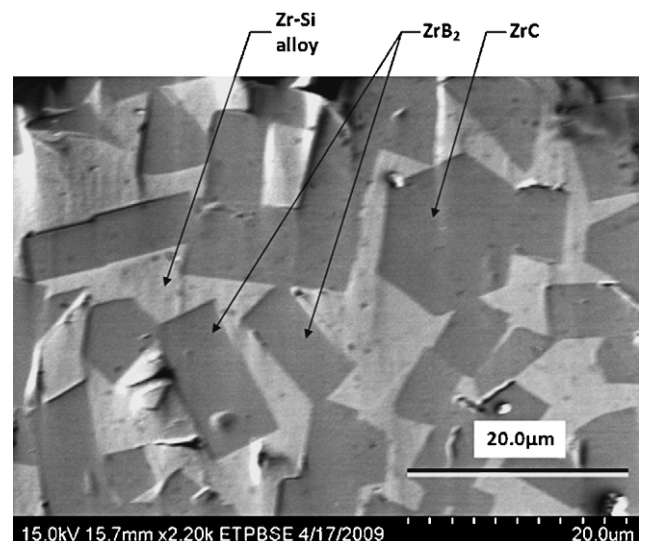


Fig. 15. A scanning electron microscope image of a ZrB₂/ZrC/Zr–Si composite experimentally acquired by reacting a Zr–Si liquid with B₄C.

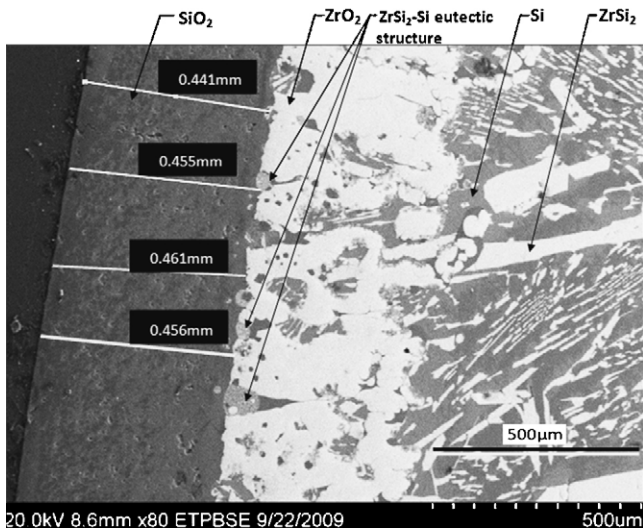


Fig. 16. A microstructure of a SiO₂ layer enveloping a Zr silicide liquid.

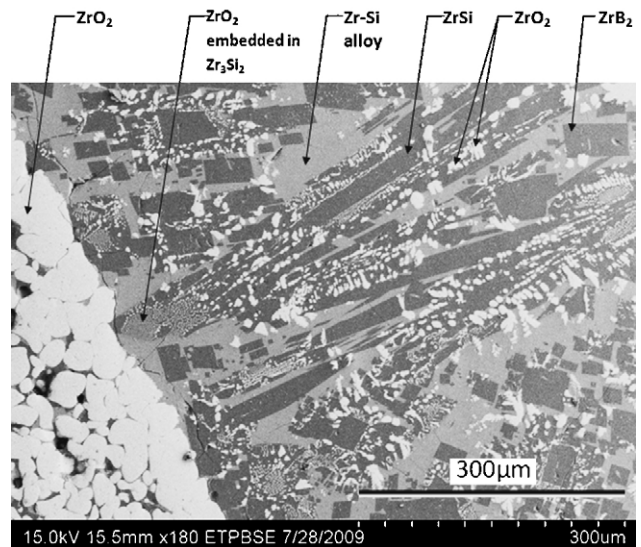


Fig. 17. A microstructure depicting a ZrO₂ layer adjacent to a Zr–Si melt containing ZrB₂.

composite was then heated to 1973 K in air, but disintegrated upon oxidation. The duplex scale consisting of SiO₂ and ZrO₂ layers did not develop adequately to protect the composite.

To determine the efficacy of the silica layer, a Zr/ZrSi₂ mixture was placed in a quartz ampoule of 1 mm thickness and then evacuated to create Zr/ZrSi₂/SiO₂ couple. The microstructure of the Zr/ZrSi₂/SiO₂ couple indicates that the silicate layer protects the couple from oxidation in air, as shown in Fig. 16. The silica layer was less than 1 mm as a result of some vaporization as well as the fluid nature of the quartz wall moving at 1700 °C. Hence, the ZrC/ZrB₂/Zr–Si composite may develop sufficient porosity during ramping toward 1973 K to cause pesting, which can be circumvented with a fluid SiO₂ sealant.

The microstructure of the Zr/ZrSi₂/SiO₂ couple also shows that SiO₂, ZrO₂ and a Zr–Si melt developed at 1700 °C, as evident from ZrSi₂–Si eutectic structure between the ZrO₂ and SiO₂ phases. Oxygen permeated sufficiently through the SiO₂ layer and reacted with Zr within the silicide melt to form ZrO₂ with adequate growth to encase colonies of ZrSi₂–Si eutectic. The original composition of Zr and ZrSi₂ mixture amounted to 77 wt% Zr (or 0.51 at% Zr) for a Zr content near the ZrSi compound within the interior of the ampoule. The silicide melt formed during the 44 h anneal because upon cooling the melt solidified without forming ZrSi and precipitated hypo-eutectic ZrSi₂ with the ZrSi₂–Si eutectic microstructure, as shown in Fig. 16. Although a portion of the Zr content within the silicide melt was consumed by its oxidation to ZrO₂, its formation created three phases consisting of ZrO₂, SiO₂ and Zr–Si(liq). The Zr–Si–O phase diagram at 1973 K indicates that an oxygen potential approximating 10^{−16.5} atm was achieved at the ZrSi₂–Si structures located along silica interface, as suggested by the silicide melt–silica equilibrium (Fig. 4).

For the encapsulated ZrB₂/ZrC/Zr–Si composite, the microstructure indicates a layer of ZrO₂ grains adjacent to the composite in which ZrB₂ precipitates are evident, as shown in Fig. 17. The ZrO₂ grains may result from their transformations occurring from 1700 °C to room temperature as the zirconia pro-

ceeds through the cubic, tetragonal and monoclinic phases with silica located between the grains. In addition, the silica layer acquired from the collapsed quartz wall enveloping the composite limits oxidation. The two-phase equilibrium consisting of silicide and silica, developing with approximately 10^{−16.5} atm, does seem to limit the oxygen ingress into the interior. The three-phase equilibria of ZrO₂, ZrSi, and Zr₃Si₂ also suggests that ZrO₂, ZrSi, and Zr₅Si₃ developed or ZrSi–ZrO₂–Zr₅Si₃(O) coexisted at 1700 °C. The oxygen content within a Zr–Si–O system may stabilize the Zr₅Si₃ as Brewer and Kirkorian⁴¹ first reported and later confirmed by Sorrell and McCartney.⁴² With ZrSi–ZrO₂–Zr₅Si₃ equilibrium, the oxygen potential of 10^{−18} atm is approached within the interior of the composite. With decreasing temperature, the Zr₅Si₃ becomes unstable and will decompose to Zr₃Si₂, but the Zr₅Si₄ phase was curiously not observed and perhaps the cooling from 1700 °C hampered its precipitation as expected by reaction (3). The microstructure does indicate that ZrB₂ precipitates do not oxidize as a result of the silicide/oxide phases fixing oxygen potentials of 10^{−16.5} to 10^{−18} atm.

In summary, the computational modeling suggested that the silicide precipitates along the scale/matrix interface did not cause a significant local strain energy, which probably was minimized by the metal fraction. The simulations using the enriched finite element method did determine that 1.96 µm as the optimal spacing of ZrO₂ precipitates within the silica layer. However, in oxidation of a ZrB₂/ZrC/Zr–Si composite to develop the silica layer, the composite disintegrated upon oxidation because the Zr–Si alloy did not form an adequate silica layer and within it sufficient porosity may have developed. Experiments actually determined that when a silica layer surrounded a silicide or a composite, oxidation was minimized at 1700 °C. Although the oxygen ingress was controlled by the oxygen gradient, the oxygen potentials established on either side of scale by phase equilibria serves to limit oxidation.

6. Conclusions

The study has determined that the size of the ZrB₂ and ZrC precipitates creates a maximum strain on the substrate with the use of conventional finite element analysis, which was applied to create a baseline for the enriched finite element method. The model of the Zr boride/carbide composite with a SiO₂/ZrO₂/ZrSi_x scale simulates the development of the strain energetics under a thermal load from 300 to 1700 K. The computational analysis determined that the size of the SiO₂ and ZrSi_x precipitates does not appreciably influence the durability of the microstructure. A simulated annealing optimization algorithm was also developed for an extended finite element program (called XMicro) with the purpose of optimizing the auto re-meshing of XMicro and thus minimizing its combinatorial selection of a composite's reinforcement architecture. After correcting for the overlapping of ZrO₂ precipitates within a matrix, XMicro determined that 1.96 μm as the optimal spacing of precipitates within a cluster and 20 μm between clusters within a silica matrix of the scale interphase. The ZrC/ZrB₂/Zr–Si composite appear to sustain pesting upon oxidizing in air at 1700 °C. However, a Zr/ZrSi₂/SiO₂ couple annealed at 1700 °C for more than 48 h indicates that the silicate layer protects the couple from oxidation. The strategic experimentation determined that porosity developed during oxidation should be incorporated into the simulation of a ceramic composite. The computational mechanics coupled with consideration of the thermodynamic stability of phases for the Zr–Si–O system to set the oxygen potentials between layers can design a scale interphase for an ultrahigh-temperature, ceramic composite system. The processing challenge may be to attain the optimal configuration of the microstructure (e.g., ZrO₂ clusters within a silicate phase).

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